

RGP10AG THRU RGP10MG

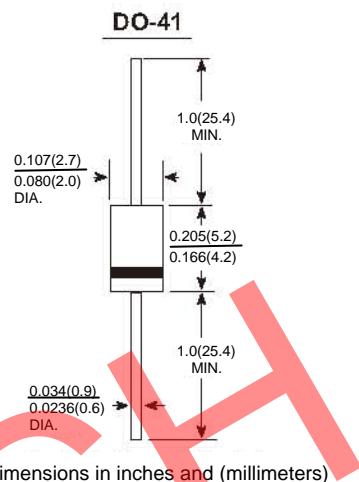
GLASS PASSIVATED FAST RECOVERY RECTIFIER

Reverse Voltage – 50 to 1000 V

Forward Current – 1 A

Features

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Fast switching for high efficiency
- Low reverse leakage
- High forward surge current capability



Mechanical Data

- Case:** JEDEC DO-41 molded plastic body
- Terminals:** Plated axial leads, solderable per MIL-STD-750, method 2026
- Polarity:** Color band denotes cathode end
- Mounting Position:** Any

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

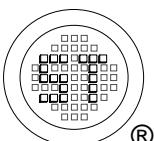
Single phase, half wave, 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	Symbols	RGP 10AG	RGP 10BG	RGP 10DG	RGP 10GG	RGP 10JG	RGP 10KG	RGP 10MG	Units
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A = 75^\circ\text{C}$	$I_{F(AV)}$					1.0			A
Peak forward surge current 8.3 mS single half sine-wave superimposed on rated load(JEDEC Method)	I_{FSM}					30			A
Maximum instantaneous forward voltage at 1.0A	V_F				1.3				V
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage $T_A = 100^\circ\text{C}$	I_R				5.0				μA
Maximum reverse recovery time ¹⁾	t_{rr}			150		250		500	ns
Typical junction capacitance ²⁾	C_J				15				pF
Typical thermal resistance ³⁾	$R_{\theta JA}$				50				$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{Stg}				-65 to +150				$^\circ\text{C}$

¹⁾ Reverse recovery condition $I_F = 0.5 \text{ A}$, $I_R = 1.0 \text{ A}$, $I_{rr} = 0.25 \text{ A}$.

²⁾ Measured at 1.0 MHz and applied reverse voltage of 4.0 VDC.

³⁾ Thermal resistance from junction to ambient at 0.375"(9.5mm) lead length, P.C. board mounted.



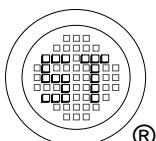
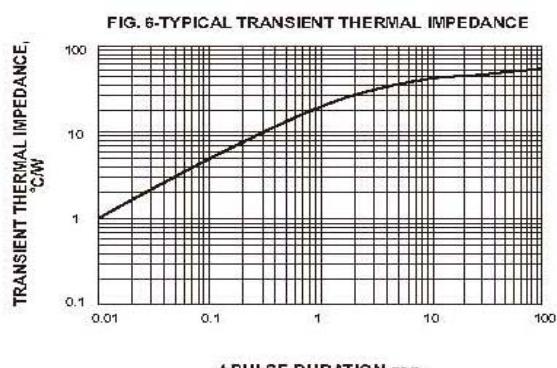
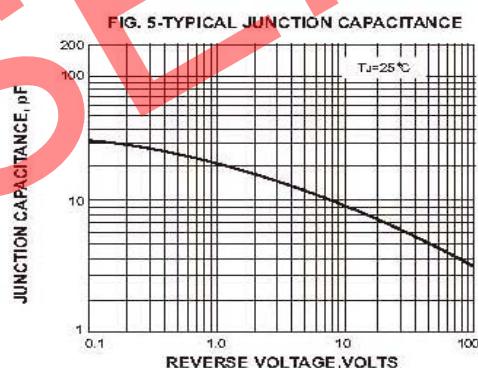
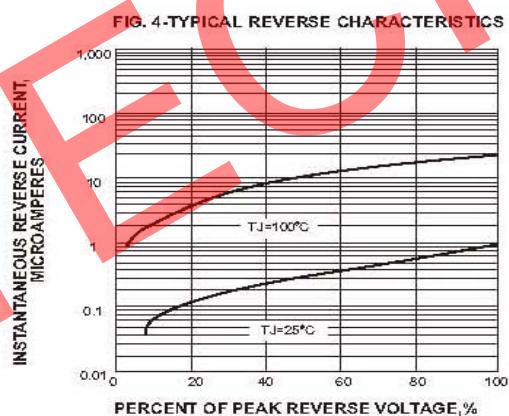
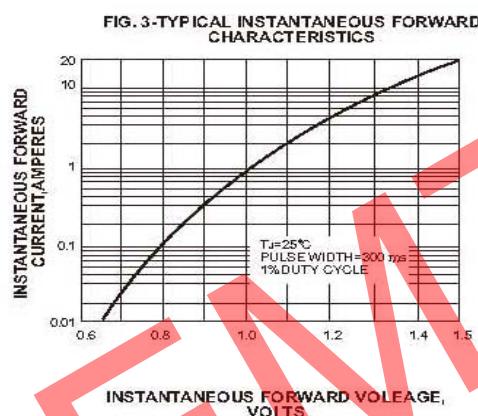
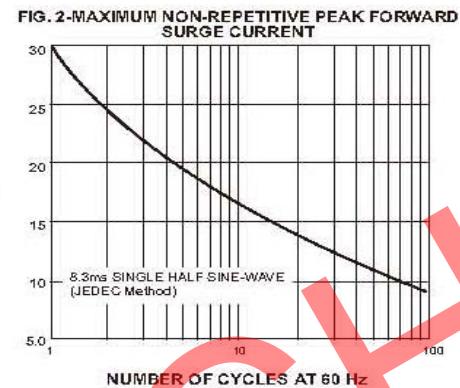
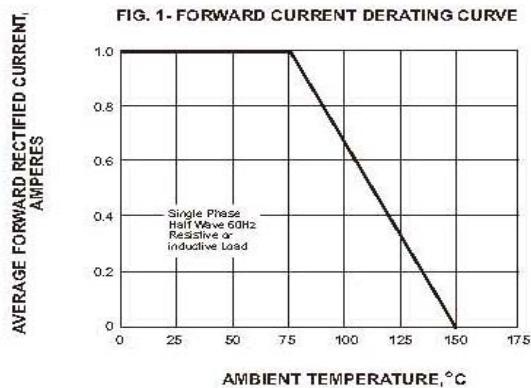
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ISO TS 16949 - 2009 Certificate No. M-5912492 ISO 14001 : 2004 Certificate No. 7118 ISO 9001 : 2008 Certificate No. 050098 BS EN 61000-4-2006 Certificate No. 7116 IECQ QC 080000 Certificate No. PCHP94-M01

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